

CMOS Multifunction Expandable 8-Input Gate

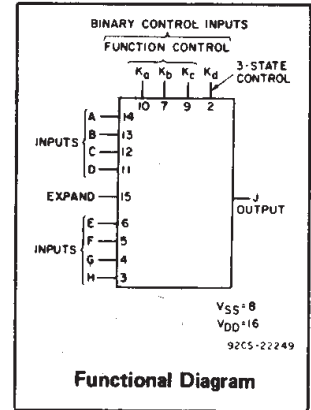
High-Voltage Types (20-Volt Rating)

■ CD4048B is an 8-input gate having four control inputs. Three binary control inputs — Ka, Kb, and Kc — provide the implementation of eight different logic functions. These functions are OR, NOR, AND, NAND, OR/AND, OR/NAND, AND/OR and AND/NOR.

A fourth control input, Kd, provides the user with a 3-state output. When control input Kd is high, the output is either a logic 1 or a logic 0 depending on the inner states. When control input Kd is low, the output is an open circuit. This feature enables the user to connect this device to a common bus line.

In addition to the eight input lines, an EXPAND input is provided that permits the user to increase the number of inputs into a CD4048B (see Fig. 2). For example, two CD4048B's can be cascaded to provide a 16-input multifunction gate. When the EXPAND input is not used, it should be connected to VSS.

The CD4048B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).



MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V _{DD})		
Voltages referenced to V _{SS} Terminal	-0.5V to +20V	
INPUT VOLTAGE RANGE, ALL INPUTS	-0.5V to V _{DD} +0.5V	
DC INPUT CURRENT, ANY ONE INPUT	±10mA	
POWER DISSIPATION PER PACKAGE (P _D):		
For T _A = -55°C to +100°C	500mW	
For T _A = +100°C to +125°C	Derate Linearity at 12mW/°C to 200mW	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR		
FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100mW	
OPERATING-TEMPERATURE RANGE (T _A)	-55°C to +125°C	
STORAGE TEMPERATURE RANGE (T _{sig})	-65°C to +150°C	
LEAD TEMPERATURE (DURING SOLDERING):		
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max	+265°C	

Features:

- Three-state output
- Many logic functions available in one package
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V (full package-temperature range), 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = 1 V at V_{DD}=5 V, 2 V at V_{DD} = 10 V, 2.5 V at V_{DD}=15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Selection of up to 8 logic functions
- Digital control of logic
- General-purpose gating logic
 - Decoding
 - Encoding

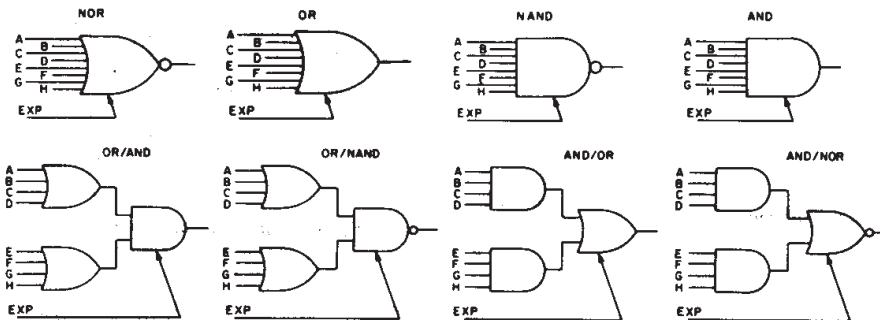


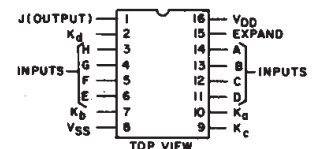
Fig. 1 - Basic logic configurations.

92CM-22250

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range (For T _A = Full Package Temperature Range)	3	18	V



92CS-20246R1

TERMINAL ASSIGNMENT

3
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CD4048B Types

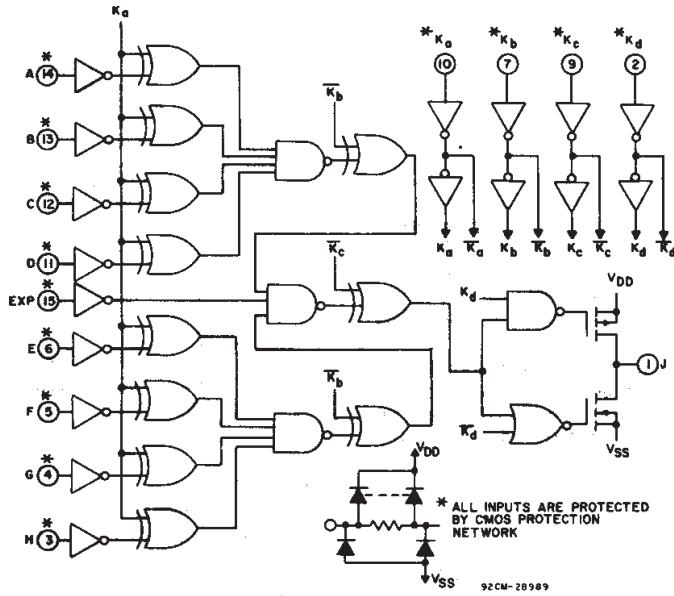


Fig. 2 - Logic diagram.

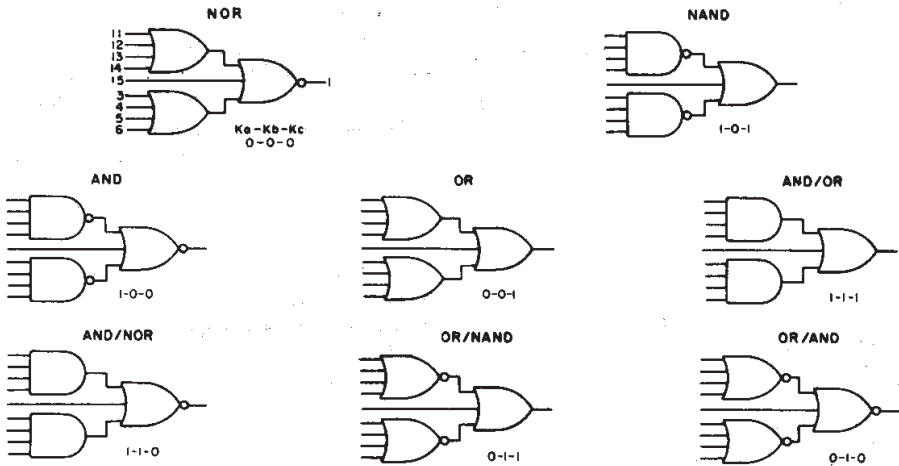


Fig. 3 - Actual-circuit logic configurations.

APPLICATIONS OF EXPAND INPUT

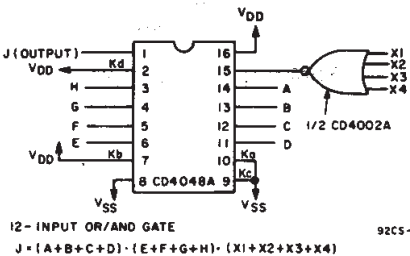


Fig. 4 - 12-input OR/AND gate.

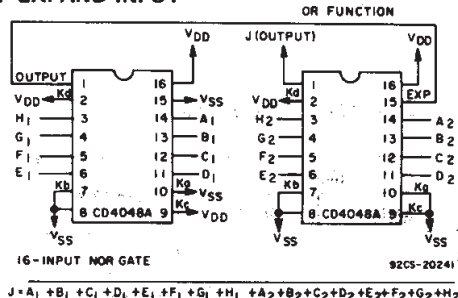


Fig. 5 - 16-input NOR gate.

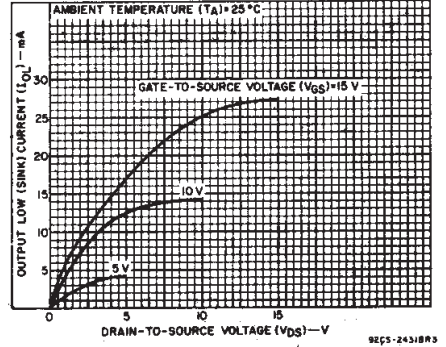


Fig. 6 - Typical output low (sink) current characteristics.

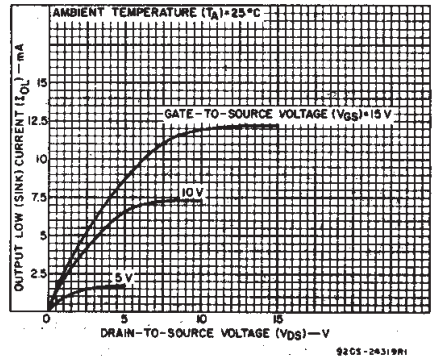


Fig. 7 - Minimum output low (sink) current characteristics.

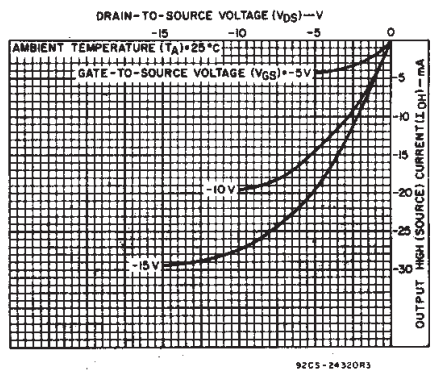


Fig. 8 - Typical output high (source) current characteristics.

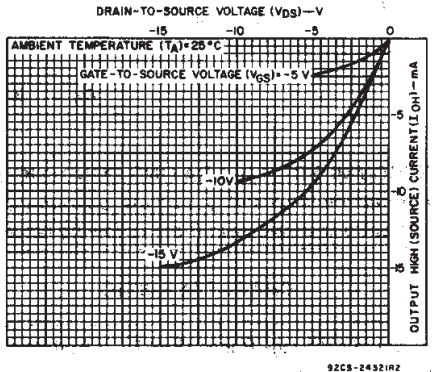


Fig. 9 - Minimum output high (source) current characteristics.

CD4048B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	+25							
				-55	-40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	—	0,5	5	0.25	0.25	7.5	7.5	—	0.01	0.25	μA
	—	0,10	10	0.5	0.5	15	15	—	0.01	0.5	
	—	0,15	15	1	1	30	30	—	0.01	1	
	—	0,20	20	5	5	150	150	—	0.02	5	
Output Low (Sink) Current, I _{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I _{OH} Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0,5	5	0.05				—	0	0.05	V
	—	0,10	10	0.05				—	0	0.05	
	—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	—	0,5	5	4.95				4.95	5	—	V
	—	0,10	10	9.95				9.95	10	—	
	—	0,15	15	14.95				14.95	15	—	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	—	5	1.5				—	—	1.5	V
	1,9	—	10	3				—	—	3	
	1.5, 13.5	—	15	4				—	—	4	
Input High Voltage, V _{IH} Min.	0.5, 4.5	—	5	3.5				3.5	—	—	V
	1,9	—	10	7				7	—	—	
	1.5, 13.5	—	15	11				11	—	—	
Input Current I _{IN} Max.		0,18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA
3-State Output Current, I _{OUT}	0,18	0,18	18	±0.4	±0.4	±12	±12	—	±10 ⁻⁴	±0.4	μA

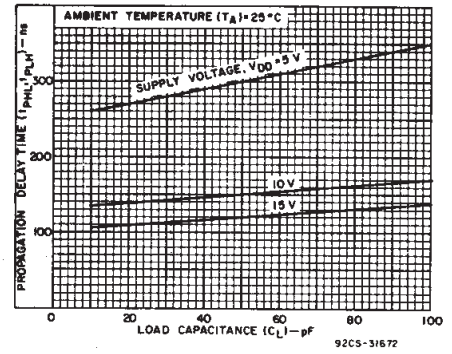


Fig. 10 – Typical propagation delay time (logic inputs to output) as a function of load capacitance.

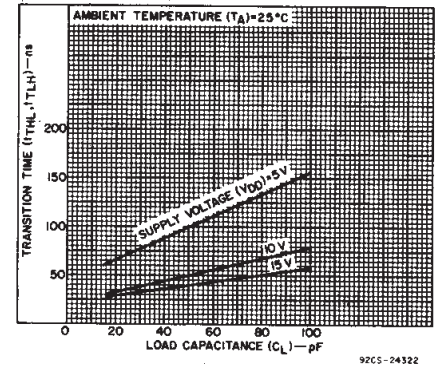


Fig. 11 – Typical transition time vs. load capacitance.

IMPLEMENTATION OF EXPAND INPUT FOR 9 OR MORE INPUTS

OUTPUT FUNCTION	FUNCTION NEEDED AT EXPAND INPUT	OUTPUT BOOLEAN EXPRESSION
NOR	OR	$J = (A+B+C+D+E+F+G+H) + (EXP)$
OR	OR	$J = (A+B+C+D+E+F+G+H) + (EXP)$
AND	NAND	$J = (ABCDEFHG) \cdot (EXP)$
NAND	NAND	$J = (ABCDEFHG) \cdot (EXP)$
OR/AND	NOR	$J = (A+B+C+D) \cdot (E+F+G+H) \cdot (EXP)$
OR/NAND	NOR	$J = (A+B+C+D) \cdot (E+F+G+H) \cdot (EXP)$
AND/NOR	AND	$J = (ABCD) + (EFGH) + (EXP)$
AND/OR	AND	$J = (ABCD) + (EFGH) + (EXP)$

Note: (EXP) designates the EXPAND function (i.e., $X_1 + X_2 + \dots + X_N$).

NOTE:
Refer to FUNCTION TRUTH TABLE for connection of unused inputs.

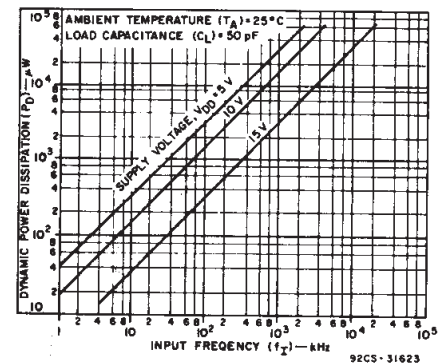


Fig. 12 – Typical power dissipation as a function of input frequency.

CD4048B Types

DYNAMIC CHARACTERISTICS at $T_A=25^{\circ}\text{C}$, $C_L=50\text{ pF}$, Input $t_r, t_f=20\text{ ns}$, $R_L=200\text{ k}\Omega$ unless otherwise specified

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS	
		V_{DD} V	All Package Types		
			Typ.	Max.	
Propagation Delay: t_{PHL}, t_{PLH} Inputs to Output and Ka to Output		5	300	600	ns
		10	150	300	
		15	120	240	
Kb to Output		5	225	450	
		10	85	170	
		15	55	110	
Kc to Output		5	140	280	
		10	50	100	
		15	40	80	
Expand Input to Output		5	190	380	
		10	90	180	
		15	65	130	
3-State Propagation Delay: Kd to Output t_{PHZ}, t_{PLZ} t_{PZH}, t_{PZL}	$R_L=1\text{ k}\Omega$ See Fig.21	5	80	160	
		10	35	70	
		15	25	50	
Transition Time: t_{THL}, t_{TLH}		5	100	200	
		10	50	100	
		15	40	80	
Input Capacitance: C_i	Any Input		5	7	pF
3-State Output Capacitance			5	10	

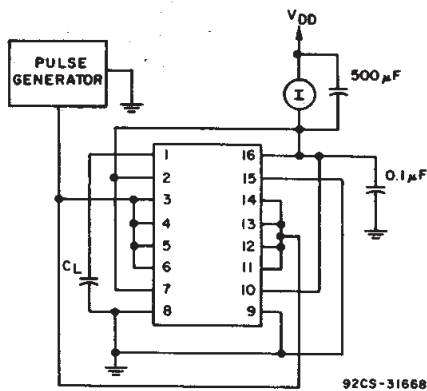


Fig. 13 - Dynamic power dissipation test circuit.

FUNCTION TRUTH TABLE

OUTPUT FUNCTION	BOOLEAN EXPRESSION	K_a	K_b	K_c	UNUSED INPUT*
NOR	$J = \overline{A+B+C+D+E+F+G+H}$	0	0	0	V_{SS}
OR	$J = A+B+C+D+E+F+G+H$	0	0	1	V_{SS}
OR/AND	$J = (A+B+C+D) \cdot (E+F+G+H)$	0	1	0	V_{SS}
OR/NAND	$J = (A+B+C+D) \cdot \overline{(E+F+G+H)}$	0	1	1	V_{SS}
AND	$J = ABCDEFGH$	1	0	0	V_{DD}
NAND	$J = \overline{ABCDEFGH}$	1	0	1	V_{DD}
AND/NOR	$J = \overline{ABCD} + EFGH$	1	1	0	V_{DD}
AND/OR	$J = ABCD + EFGH$	1	1	1	V_{DD}
$K_d=1$ Normal Inverter Action					
$K_d=0$ High Impedance Output					

EXPAND Input=0

* See Figs. 1,2,3,4, and 5.

TEST CIRCUITS - STATIC MEASUREMENTS

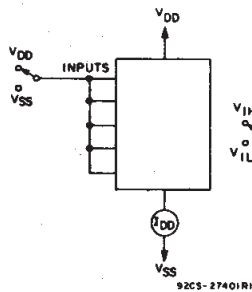


Fig. 14 - Quiescent device current test circuit.

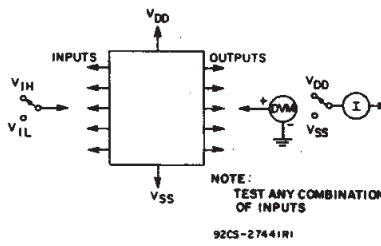


Fig. 15 - Input voltage test circuit.

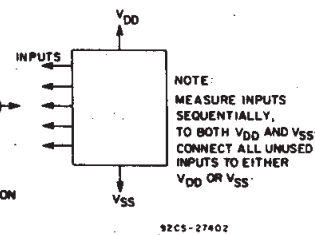


Fig. 16 - Input current test circuit.

CD4048B Types

TEST CIRCUITS - DYNAMIC MEASUREMENTS

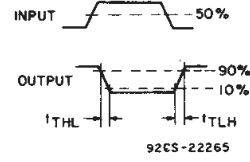
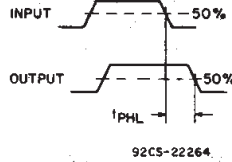
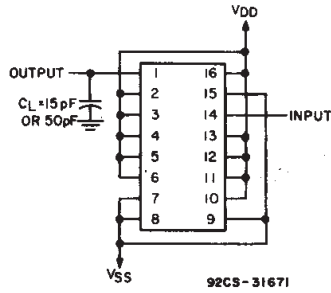


Fig. 17 - Test circuit for t_{PHL} , t_{THL} , and t_{TLH} (AND) measurements.

Fig. 18 - Waveforms for t_{PHL} and t_{PHL} (AND).

Fig. 19 - Waveforms for t_{THL} and t_{TLH} (AND).

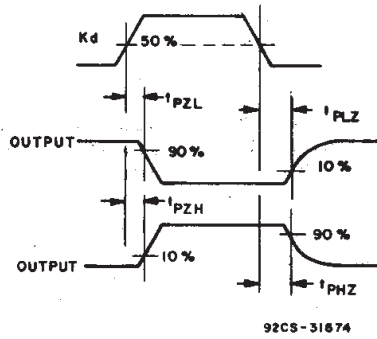
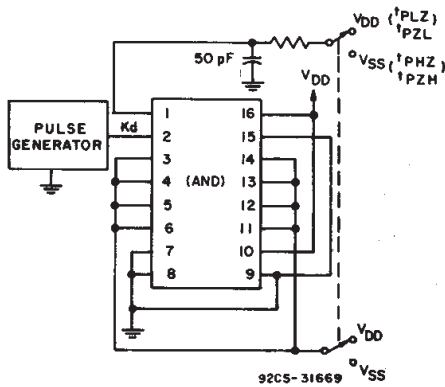
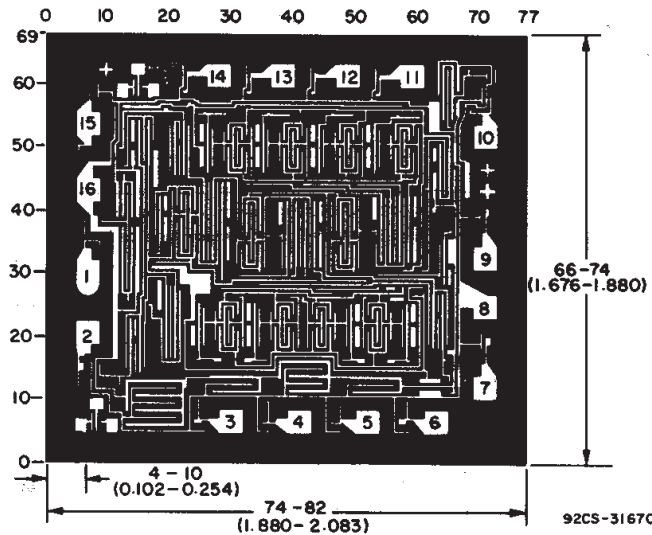


Fig. 20 - Test circuit for t_{PZL} , t_{PZH} , t_{PLZ} , and t_{PHZ} (AND).

Fig. 21 - Waveforms for t_{PZL} , t_{PZH} , t_{PLZ} , and t_{PHZ} (AND).



Dimensions and pad layout for CD4048BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

3
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